General Description

The LTA8291, LTA8292 and LTA8294 (LTA829x) are a family of low power, 48 V wide supply voltage, low noise, rail-to-rail output operational amplifiers capable of operating on supplies ranging from ± 4.5 V (± 2.25 V) to ± 4.8 V (± 2.4 V). This new generation of high-voltage CMOS operational amplifiers, in conjunction with the LTA828x, LTA827x and LTA826x, provide a family of bandwidth, noise, and power options to meet the needs of a wide variety of applications. The LTA829x devices offer outstanding dc precision and ac performance, including low offset (± 1.8 mV maximum), low offset drift (± 2 μ V/°C typically), 22 MHz bandwidth, and 4 nV/ \pm Hz input voltage noise density at 10 kHz. Unique features such as differential input-voltage range to the negative supply rail, high output current (± 4.5 mA), high capacitive load drive of up to 1 nF, and high slew rate (20 V/ μ s) make the LTA829x high-performance operational amplifiers for high-voltage industrial applications.

The robust design of the LTA829x family provides ease-of-use to the circuit designer: integrated RF/EMI rejection filter, no phase reversal in overdrive conditions, and high electro-static discharge (ESD) protection. The LTA829x are optimized for operation at voltages from +4.5 V (± 2.25 V) to +48 V (± 2.4 V) over the extended temperature range of -40 °C to +125 °C.

Features and Benefits

Wide Supply: ±2.25 V to ±24 V, 4.5 V to 48 V

Wide Bandwidth: 22 MHz GBW

High Slew Rate: 20 V/μs

■ Low Noise: 4 nV/√Hz at 10 kHz

Low Offset Voltage: ±1.8 mV Maximum

Low Offset Voltage Drift: ±2 μV/°C

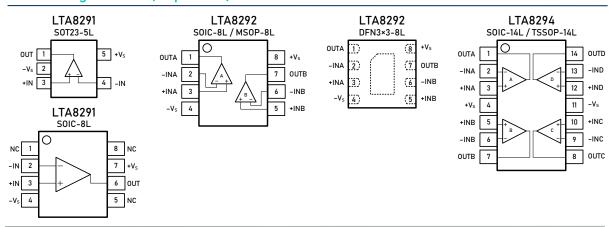
■ High Common-Mode Rejection: 115 dB

Low Bias Current: ±10 pAEMI/RFI Filtered Inputs

Applications

- High-Side and Low-Side Current Sensing
- Audio Preamplifier
- High Precision Comparator
- Multiplexed Data-Acquisition Systems
- High-Resolution ADC Driver Amplifiers
- SAR ADC Reference Buffers
- Test and Measurement Equipment
- Programmable Logic Controllers

Pin Configuration (Top View)





Pin Description

Symbol	Description
-IN	Inverting input of the amplifier. The voltage range is from V_{S-} to V_{S+} – 1.5 V.
+IN	Non-inverting input of the amplifier. This pin has the same voltage range as -IN.
+V _S	Positive power supply. The voltage is from 4.5 V to 48 V. Split supplies are possible as long as the voltage between V_{S+} and V_{S-} is from 4.5 V to 48 V.
-V _S	Negative power supply. It is normally tied to ground. It can also be tied to a voltage other than ground as long as the voltage between V_{S+} and V_{S-} is from 4.5 V to 48 V.
OUT	Amplifier output.
NC	No connection

Ordering Information (1)

Type Number	Package Name	Package Quantity	Eco Class ⁽²⁾	Marking Code ⁽³⁾
LTA8291XT5/R6	S0T23-5L	Tape and Reel, 3 000	Green (RoHS & no Sb/Br)	H91
LTA8291XS8/R8	SOIC-8L	Tape and Reel, 4 000	Green (RoHS & no Sb/Br)	HV-91
LTA8292XS8/R8	SOIC-8L	Tape and Reel, 4 000	Green (RoHS & no Sb/Br)	HV-92
LTA8292XV8/R6	MSOP-8L	Tape and Reel, 3 000	Green (RoHS & no Sb/Br)	HV92
LTA8292XF8/R10	DFN3x3-8L	Tape and Reel, 3 000	Green (RoHS & no Sb/Br)	HV92
LTA8294XS14/R5	SOIC-14L	Tape and Reel, 2 500	Green (RoHS & no Sb/Br)	HV-94
LTA8294XT14/R6	TSS0P-14L	Tape and Reel, 3 000	Green (RoHS & no Sb/Br)	HV-94

- (1) Please contact to your Linearin representative for the latest availability information and product content details.
- (2) Eco Class The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & Halogen Free).
- (3) There may be multiple device markings, a varied marking character of "x", or additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

Limiting Value - In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Absolute Maximum Rating
Supply Voltage, V_{S+} to V_{S-}	60 V
Signal Input Terminals: Voltage, Current	$-V_S$ - 0.3 V to +V $_S$ + 0.3 V, ± 10 mA
Output Short-Circuit	Continuous
Storage Temperature Range, T _{stg}	-65 °C to +150 °C
Junction Temperature, T _J	150 °C
Lead Temperature Range (Soldering 10 sec)	260 °C

ESD Rating

Parameter	Item	Value	Unit
Electrostatic Discharge Voltage	Human body model (HBM), per MIL-STD-883J / Method 3015.9 ⁽¹⁾	2 000	- V
	Charged device model (CDM), per ESDA/JEDEC JS-002-2014 (2)	2 000	– v

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible if necessary precautions are taken.



⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible if necessary precautions are taken.

Electrical Characteristics

 V_S = 4.5 V to 48 V, T_A = +25 °C, V_{CM} = V_{OUT} = $V_S/2$, and R_L = 10 k Ω connected to $V_S/2$, unless otherwise noted. Boldface limits apply over the specified temperature range, T_A = -40 °C to +125 °C.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
OFFSET VOLTAGE							
Input offset voltage	V _{os}	7. (0) 407.00		±0.5	±1.8	mV	
Offset voltage drift	V _{os} TC	T _A = -40 to +125 °C		±2		μV/°C	
Power supply rejection ratio	PSRR	$V_S = 4.5 \text{ to } 48 \text{ V}, V_{CM} = 0.1 \text{ V}$		5		μV/V	
		T _A = -40 to +125 °C		10			
INPUT BIAS CURRENT				10			
In mod blog a command		T		10			
Input bias current	I _B	$T_A = -40 \text{ to } +85 \text{ °C}$		150		pA	
Innuit officet accurant		T _A = -40 to +125 °C		600 5		A	
Input offset current NOISE	I _{os}			ວ		pA	
	V	f = 0.1 to 10 Hz		2 4		\/	
Input voltage noise	V _n			3.6 8		μV _{P-P}	
Input voltage noise density	e_n	f = 1 kHz f = 10 kHz		4		nV/√H	
Input current noise density		f = 1 kHz		5		fA/√Hz	
INPUT VOLTAGE							
Common-mode voltage range	V _{CM}		-V _s		+V _S -1.5	V	
	^e CMRR	V _S = 40 V, V _{CM} = 0 to 38 V		115			
Common-mode		V _{CM} = 0.1 to 38 V, T _A = -40 to +125 °C		102		- -	
rejection ratio		V _S = 5 V, V _{CM} = 0 to 3 V		95		· dB	
		V _{CM} = 0.1 to 3 V, T _A = -40 to +125 °C		83			
INPUT IMPEDANCE							
		Differential		2			
Input capacitance	C _{IN}	Common mode	3.5			– pF	
OPEN-LOOP GAIN							
		V _S = 40 V, V ₀ = 0.1 to 39.9 V		126			
Open-loop voltage	٨	T _A = -40 to +125 °C		118		. 4D	
gain	A_{VOL}	$V_S = 5 \text{ V}, V_0 = 0.1 \text{ to } 4.9 \text{ V}$		116		- dB	
		$T_A = -40 \text{ to } +125 ^{\circ}\text{C}$		108		_	
FREQUENCY RESPON	SE						
Gain bandwidth product	GBW			22		MHz	
Slew rate	SR	V _S = 40 V, G = +1, 10 V step		20		V/µs	
Total harmonic distortion + noise	THD+N	G = +1, f = 1 kHz, V ₀ = 3 V _{RMS}		0.0001		%	
Settling time	+	To 0.1%, V _S = 40 V, G = +1, 5 V step		0.9			
	t _s	To 0.01%, V _S = 40 V, G = +1, 5 V step	step 2			— μs	
Overload recovery	t _{oR}	V _{IN} × Gain > V _S		0.3		μs	



Electrical Characteristics (continued)

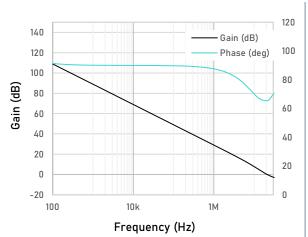
 V_S = 4 V to 48 V, T_A = +25 °C, V_{CM} = V_{OUT} = V_S /2, and R_L = 10 k Ω connected to V_S /2, unless otherwise noted. Boldface limits apply over the specified temperature range, T_A = -40 °C to +125 °C.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
OUTPUT	·	•	•	•	·	•	
High autout valtage avring	V	V_S = ± 20 V, R_L = 10 k Ω		+V _S -95		– mV	
High output voltage swing	V _{OH}	$V_S = \pm 20 \text{ V, R}_L = 2 \text{ k}\Omega$		+V _S -260		– mv	
Low output voltage swing	V	V_S = ± 20 V, R_L = 10 k Ω		-V _S +55			
Low output voltage swing	V _{oL}	V_S = ± 20 V, R_L = 2 k Ω		-V _S +240		– mV	
Short-circuit current	I _{sc}			±45		mA	
POWER SUPPLY							
Operating supply voltage	V _S	T_A = -40 to +125 °C	4.5		48	٧	
Outcome ourself (non-amplifier)	Iα	V _S = 5 V		4.2		A	
Quiescent current (per amplifier)		V _S = 40 V		7.1		– mA	
THERMAL CHARACTERISTICS							
Operating temperature range	T _A		-40		+125	°C	
		S0T23-5L		190			
		MSOP-8L		201		_	
Package Thermal Resistance	θ_{JA}	SOIC-8L		125		°C/W	
		TSS0P-14L		112		_	
		SOIC-14L		115		_	

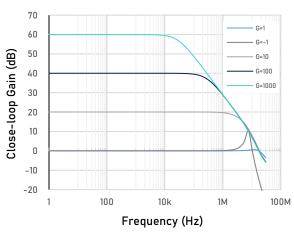


Typical Performance Characteristics

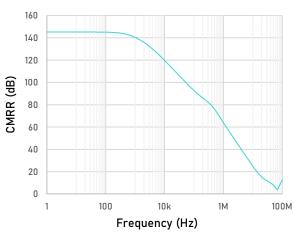
At T $_{A}$ = +25 °C, V $_{CM}$ = V $_{S}$ /2, and R $_{L}$ = 10 k Ω connected to V $_{S}$ /2, unless otherwise noted.



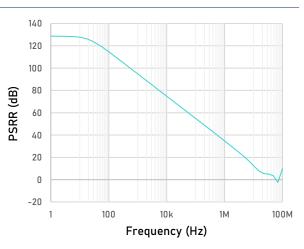
Open-loop Gain and Phase as a function of Frequency



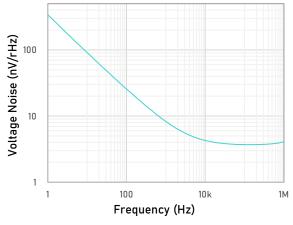
Close-loop Gain as a function of Frequency



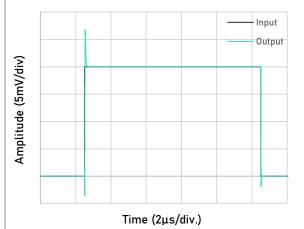
CMRR as a function of Frequency



PSRR as a function of Frequency



Input Voltage Noise Spectral Density as a function of Frequency

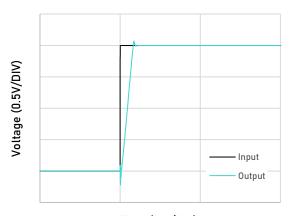


Small-Signal Step Response



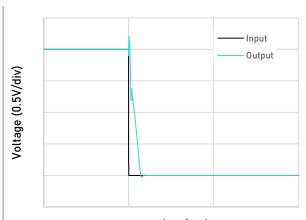
Typical Performance Characteristics (Continued)

At T_A = +25 °C, V_{CM} = $V_S/2$, and R_L = 10 k Ω connected to $V_S/2$, unless otherwise noted.



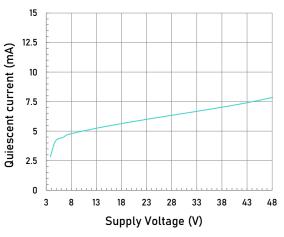
Time (1µs/div.)

Large-Signal Step Response(Rising)

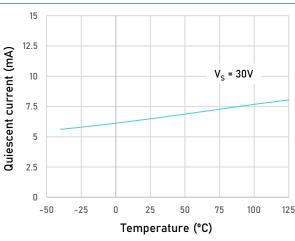


Time (1µs/div.)

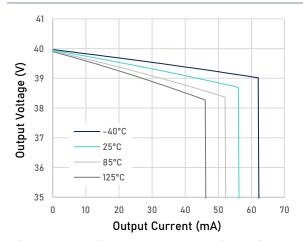
Large-Signal Step Response(Failing)



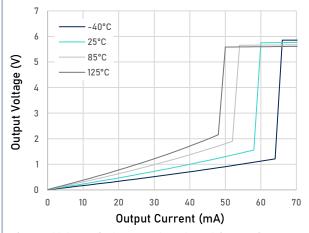
Quiescent Current as a function of Supply Voltage



Quiescent Current as a function of Temperature



Output Voltage Swing as a function of Output Current (Sourcing, $V_S = 40 \text{ V}$)

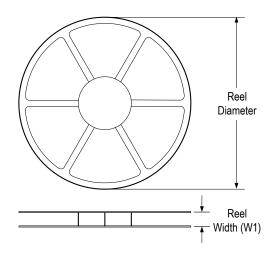


Output Voltage Swing as a function of Output Current (Sinking, $V_S = 40 \text{ V}$)

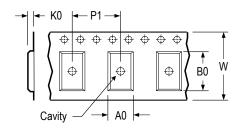


Tape and Reel Information

REEL DIMENSIONS

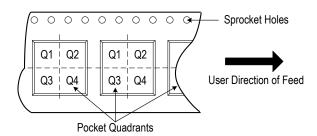


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIETATION IN TAPE



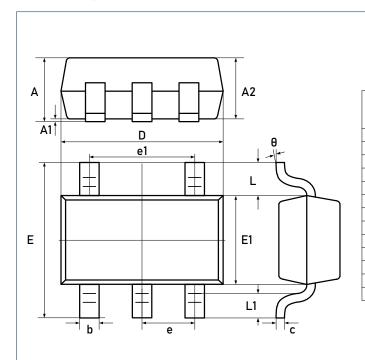
* All dimensions are nominal

Device	Package Type	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin 1 Quadrant
LTA8291XT5/R6	SOT23	5	3 000	178	9.0	3.3	3.2	1.5	4.0	8.0	Q3



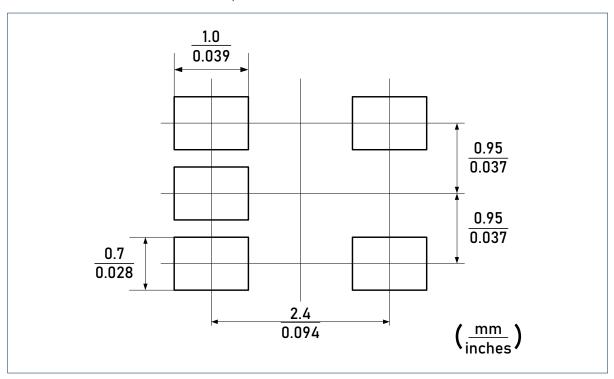
Package Outlines

DIMENSIONS, SOT23-5L



	Dimer	nsions	Dimensions		
Symbol	In Milli	meters	In Inches		
	Min	Max	Min	Max	
Α	-	1.25	-	0.049	
A1	0.04	0.10	0.002	0.004	
A2	1.00	1.20	0.039	0.047	
b	0.33	0.41	0.013	0.016	
С	0.15	0.19	0.006	0.007	
D	2.820	3.02	0.111	0.119	
E1	1.50	1.70	0.059	0.067	
E	2.60	3.00	0.102	0.118	
е	0.95	BSC	0.037 BSC		
e1	1.90	BSC	0.075	BSC	
L	0.60	REF	0.024	REF	
L1	0.30	0.60	0.012	0.024	
θ	0°	8°	0°	8°	

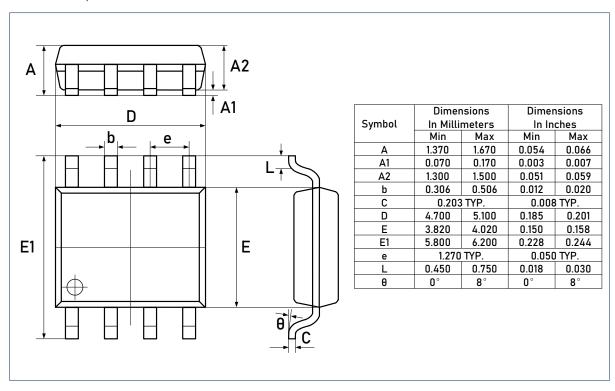
RECOMMENDED SOLDERING FOOTPRINT, SOT23-5L



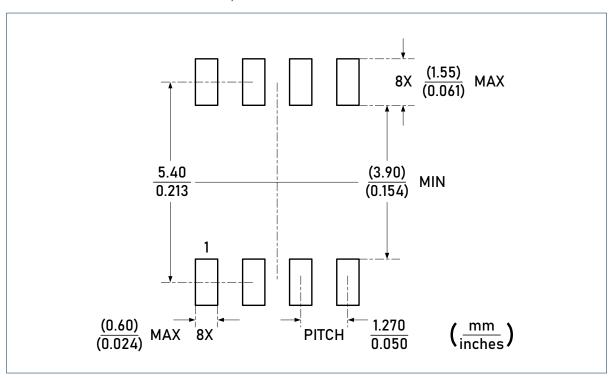


Package Outlines (continued)

DIMENSIONS, SOIC-8L



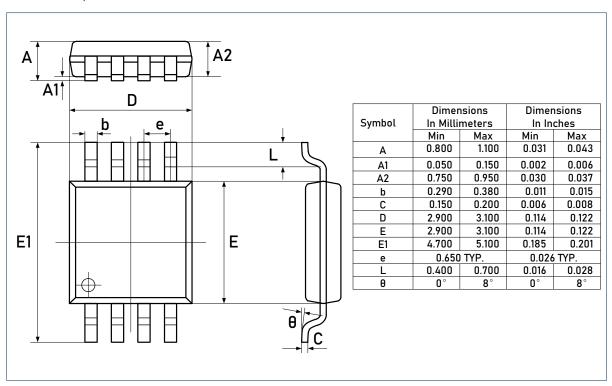
RECOMMENDED SOLDERING FOOTPRINT, SOIC-8L



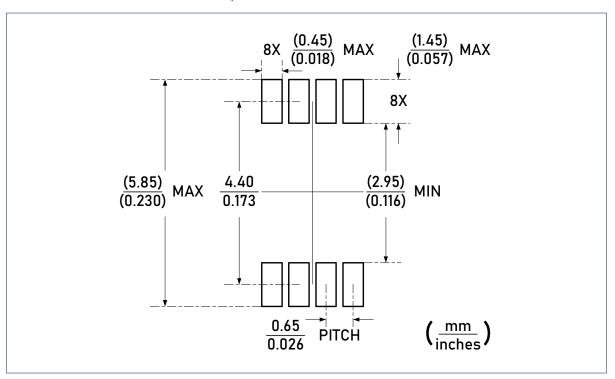


Package Outlines (continued)

DIMENSIONS, MSOP-8L



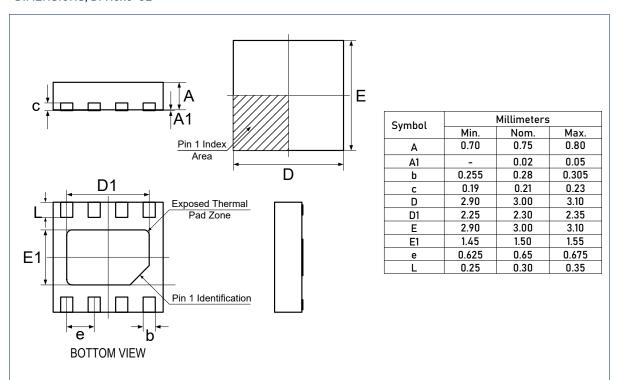
RECOMMENDED SOLDERING FOOTPRINT, MSOP-8L





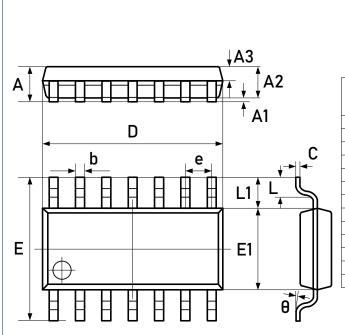
Package Outlines (continued)

DIMENSIONS, DFN3x3-8L



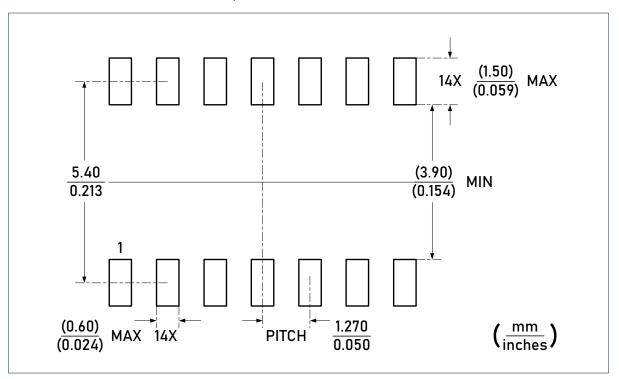
Package Outlines (continued)

DIMENSIONS, SOIC-14L



	Dimer	nsions	Dimensions		
Symbol	In Milli	meters	In Inches		
	Min	Max	Min	Max	
Α	1.450	1.850	0.057	0.073	
A1	0.100	0.300	0.004	0.012	
A2	1.350	1.550	0.053	0.061	
A3	0.550	0.750	0.022	0.030	
b	0.406	TYP.	0.016 TYP.		
С	0.203	TYP.	0.008 TYP.		
D	8.630	8.830	0.340	0.348	
Е	5.840	6.240	0.230	0.246	
E1	3.850	4.050	0.152	0.159	
е	1.270 TYP.		0.050	TYP.	
L1	1.040 REF.		0.041	REF.	
L	0.350	0.750	0.014	0.030	
А	2°	8°	2°	8°	

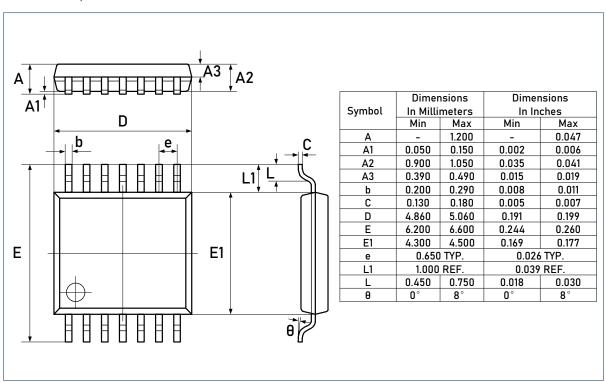
RECOMMENDED SOLDERING FOOTPRINT, SOIC-14L



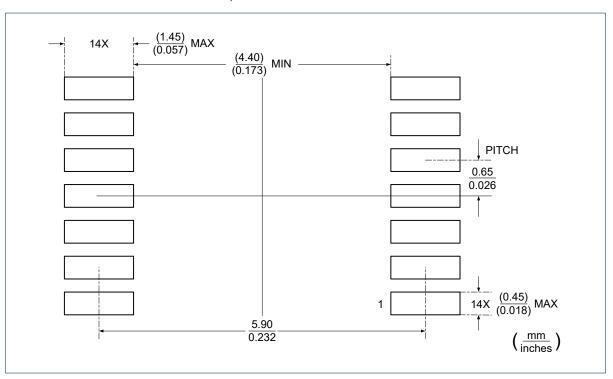


Package Outlines (continued)

DIMENSIONS, TSSOP-14L



RECOMMENDED SOLDERING FOOTPRINT, SOIC-14L





Important Notice

Linearin is a global fabless semiconductor company specializing in advanced high-performance high-quality analog/mixed-signal IC products and sensor solutions. The company is devoted to the innovation of high performance, analog-intensive sensor front-end products and modular sensor solutions, applied in multi-market of medical & wearable devices, smart home, sensing of IoT, intelligent industrial & smart factory (industrie 4.0), and automotives. Linearin's product families include widely-used standard catalog products, solution-based application specific standard products (ASSPs) and sensor modules that help customers achieve faster time-to-market products. Go to http://www.linearin.com for a complete list of Linearin product families.

For additional product information, or full datasheet, please contact with the Linearin's Sales Department or Representatives.

